

# TC7WH125FU, TC7WH125FK

## DUAL BUS BUFFER

The TC7WH125 is an advanced high speed CMOS DUAL BUS BUFFERS fabricated with silicon gate CMOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

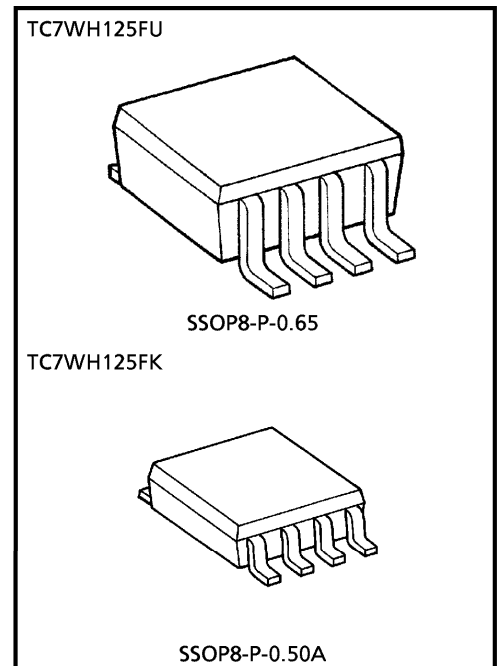
The require 3-state control input  $\bar{G}$  to be set high to place the output into the impedance.

This device is designed to be used with 3-state memory address drivers, etc.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V system and two supply system such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

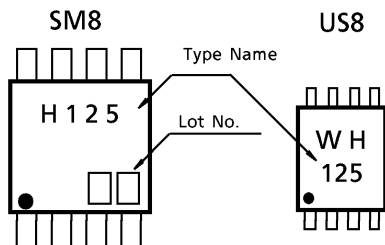
### FEATURES

- High Speed .....  $t_{pd} = 3.8ns$  (Typ.) at  $V_{CC} = 5V$
- Low Power Dissipation .....  $I_{CC} = 2\mu A$  (Max.) at  $T_a = 25^\circ C$
- High Noise Immunity .....  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays .....  $t_{pLH} \approx t_{pHL}$
- Wide Operation Voltage Range ...  $V_{CC} (opr) = 2 \sim 5.5V$
- Low Noise .....  $V_{OLP} = 0.8V$  (Max.)

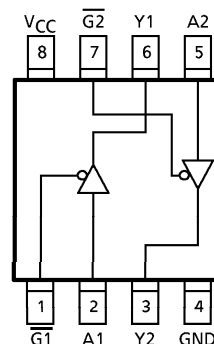


Weight  
 SSOP8-P-0.65 : 0.02g (Typ.)  
 SSOP8-P-0.50A : 0.01g (Typ.)

### MARKING



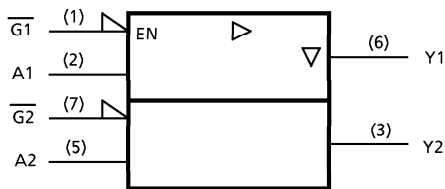
### PIN ASSIGNMENT (TOP VIEW)



**MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V <sub>CC</sub>	- 0.5~7.0	V
DC Input Voltage	V <sub>IN</sub>	- 0.5~7.0	V
DC Output Voltage	V <sub>OUT</sub>	- 0.5~V <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	- 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> /Ground Current	I <sub>CC</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	300 (SM8)	mW
		200 (US8)	
Storage Temperature	T <sub>stg</sub>	- 65~150	°C
Lead Temperature (10 s)	T <sub>L</sub>	260	°C

**LOGIC DIAGRAM**



**TRUTH TABLE**

INPUTS		OUTPUTS
$\overline{G}$	A	Y
H	x	Z
L	L	L
L	H	H

x : Don't Care  
Z : High Impedance

**RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	2~5.5	V
Input Voltage	V <sub>IN</sub>	0~5.5	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	- 40~85	°C
Input Rise and Fall Time	dt / dv	0~100 (V <sub>CC</sub> = 3.3 ± 0.3V)	ns / V
		0~20 (V <sub>CC</sub> = 5 ± 0.5V)	

**DC ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V <sub>IH</sub>	—	2.0	1.5	—	—	1.5	—	V	
			3.0~5.5	V <sub>CC</sub> × 0.7	—	—	V <sub>CC</sub> × 0.7	—		
Low-Level Input Voltage	V <sub>IL</sub>	—	2.0	—	—	0.5	—	0.5	V	
			3.0~5.5	—	—	V <sub>CC</sub> × 0.3	—	V <sub>CC</sub> × 0.3		
High-Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I <sub>OH</sub> = -4mA	3.0	2.58	—	—	2.48	—	
4.5	3.94	—		—	3.8	—				
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I <sub>OL</sub> = 4mA	3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
3-State Output Off-State Current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	5.5	—	—	± 0.25	—	± 2.5	μA	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	0~5.5	—	—	± 0.1	—	± 1.0	μA	
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	2.0	—	20.0	μA	

**AC ELECTRICAL CHARACTERISTICS (Input  $t_r = t_f = 3\text{ns}$ )**

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	MIN.	TYP.	MAX.	MIN.	MAX.		
Propagation Delay Time	t <sub>pLH</sub>	3.3 ± 0.3	15	—	5.6	8.0	1.0	9.5	ns	
			50	—	8.1	11.5	1.0	13.0		
	5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5			
		50	—	5.3	7.5	1.0	8.5			
3-State Output Enable Time	t <sub>pZL</sub>	3.3 ± 0.3	15	—	5.4	8.0	1.0	9.5	ns	
			50	—	7.9	11.5	1.0	13.0		
	5.0 ± 0.5	15	—	3.6	5.1	1.0	6.0			
		50	—	5.1	7.1	1.0	8.0			
3-State Output Disable Time	t <sub>pLZ</sub>	3.3 ± 0.3	50	—	9.5	13.2	1.0	15.0	ns	
			5.0 ± 0.5	50	—	6.1	8.8	1.0		10.0
Output to Output Skew	t <sub>osLH</sub>	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input Capacitance	C <sub>IN</sub>			—	4	10	—	10	pF	
Output Capacitance	C <sub>OUT</sub>			—	6	—	—	—	pF	
Power Dissipation Capacitance (Note 2)	C <sub>PD</sub>			—	14	—	—	—	pF	

(Note 1) : Parameter guaranteed by design.  $t_{osLH} = |t_{pLHm} - t_{pLHn}|$ ,  $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

(Note 2) : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

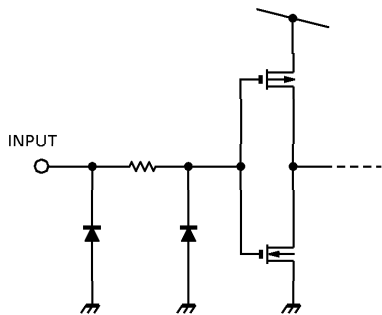
Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2 \text{ (per bit)}$$

**NOISE CHARACTERISTICS** ( $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 3\text{ns}$ )

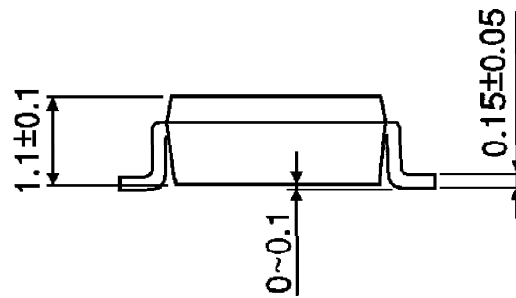
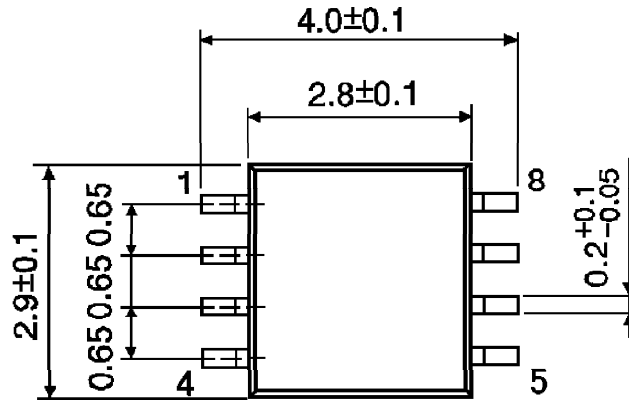
CHARACTERISTIC	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$C_L = 50\text{pF}$	5.0	0.3	0.8	V
Quiet Output Minimum Dynamic $V_{OL}$	$V_{OLV}$	$C_L = 50\text{pF}$	5.0	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	$V_{IHD}$	$C_L = 50\text{pF}$	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	$V_{ILD}$	$C_L = 50\text{pF}$	5.0	—	1.5	V

**INPUT EQUIVALENT CIRCUIT**



PACKAGE DIMENSIONS  
SSOP8-P-0.65

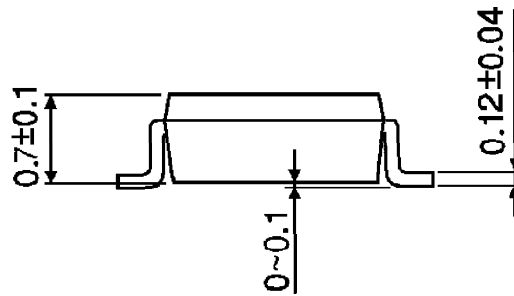
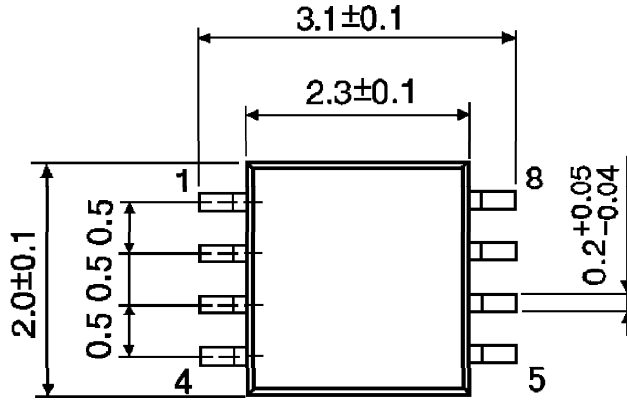
Unit : mm



Weight : 0.02g (Typ.)

PACKAGE DIMENSIONS  
SSOP8-P-0.50A

Unit : mm



Weight : 0.01g (Typ.)

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000707EBA

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